NSN 5962-01-397-5990

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Features Provided:
Monolithic and hermetically sealed and burn in
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Case Outline Source And Designator:
D-6 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
35.00 nanoseconds access
Memory Device Type:
Ram
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
18 printed circuit
Specification Data:
81349-mil-m-38510/289 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0